



FSS239

Load Switching Applications

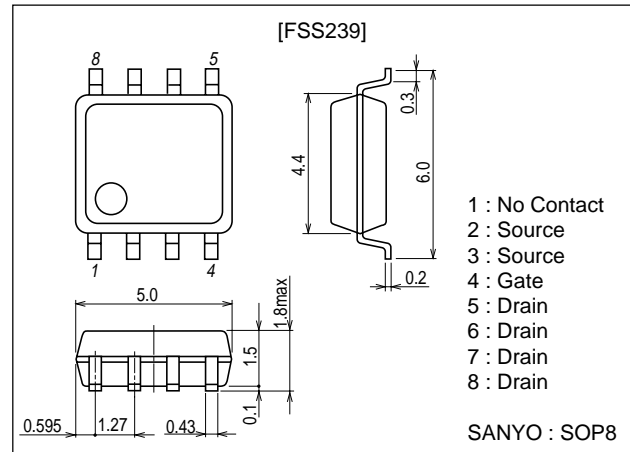
Features

- Low ON resistance.
- 2.5V drive.

Package Dimensions

unit : mm

2185



Specifications

Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|------------------|--|-------------|------|
| Drain-to-Source Voltage | V _{DSS} | | 20 | V |
| Gate-to-Source Voltage | V _{GSS} | | ±10 | V |
| Drain Current (DC) | I _D | | 7 | A |
| Drain Current (Pulse) | I _{DP} | PW≤10μs, duty cycle≤1% | 52 | A |
| Allowable Power Dissipation | P _D | Mounted on a ceramic board (1000mm²X0.8mm) | 1.8 | W |
| Channel Temperature | T _{ch} | | 150 | °C |
| Storage Temperature | T _{stg} | | -55 to +150 | °C |

Electrical Characteristics at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--|----------------------|---|---------|------|-----|------|
| | | | min | typ | max | |
| Drain-to-Source Breakdown Voltage | V _{(BR)DSS} | I _D =1mA, V _{GS} =0 | 20 | | | V |
| Zero-Gate Voltage Drain Current | I _{DSS} | V _{DS} =20V, V _{GS} =0 | | | 1 | μA |
| Gate-to-Source Leakage Current | I _{GSS} | V _{GS} =±8V, V _{DS} =0 | | | ±10 | μA |
| Cutoff Voltage | V _{GS(off)} | V _{DS} =10V, I _D =1mA | 0.4 | | 1.3 | V |
| Forward Transfer Admittance | y _{fs} | V _{DS} =10V, I _D =7A | 10.9 | 15.5 | | S |
| Static Drain-to-Source On-State Resistance | R _{DS(on)1} | I _D =7A, V _{GS} =4V | | 24 | 32 | mΩ |
| | R _{DS(on)2} | I _D =2A, V _{GS} =2.5V | | 29 | 42 | mΩ |

Marking : S239

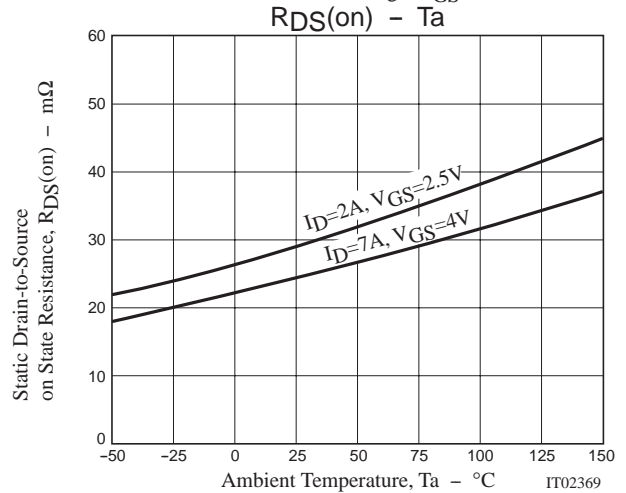
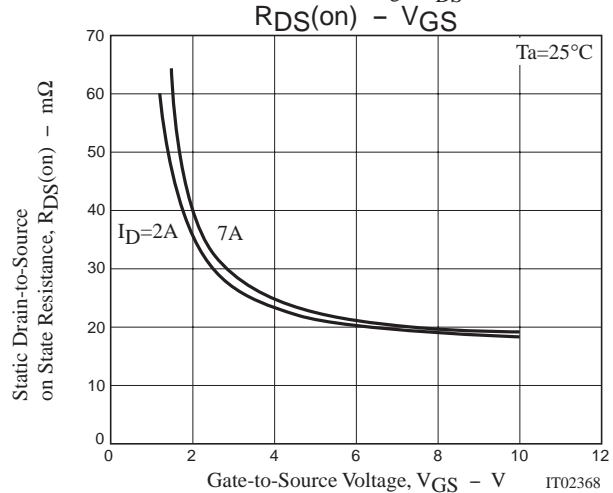
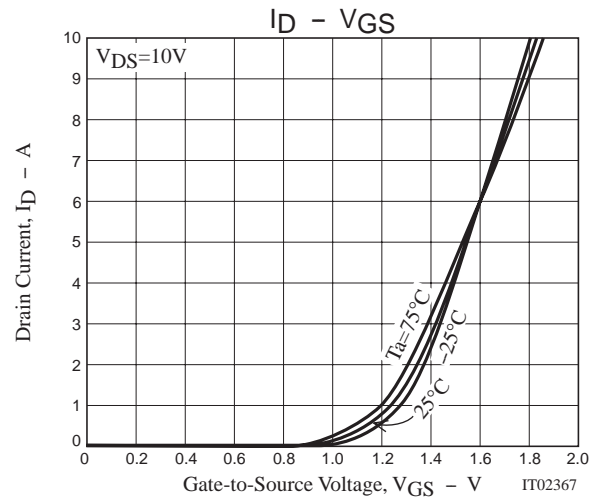
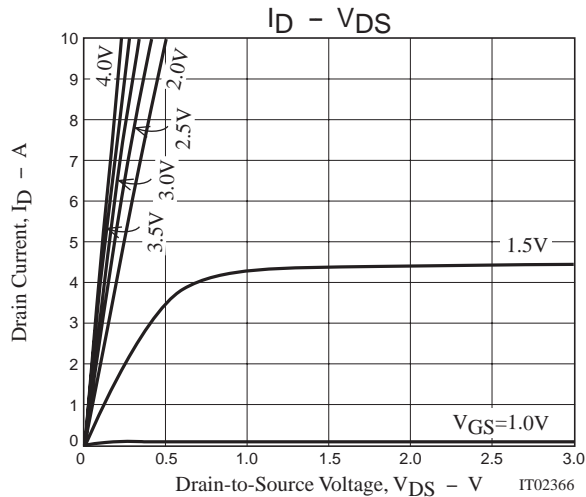
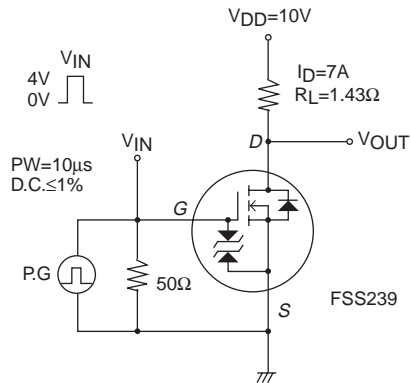
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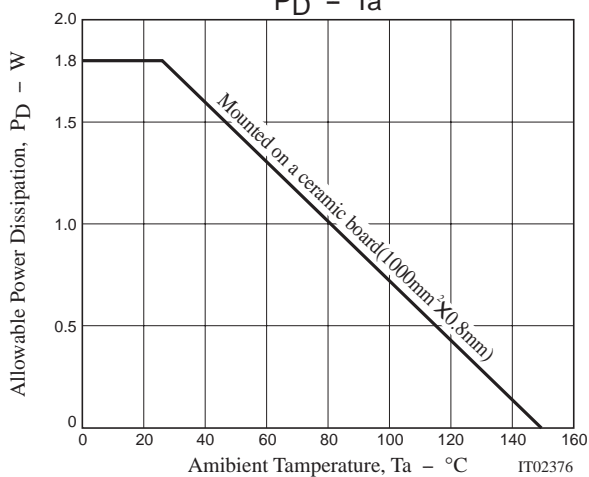
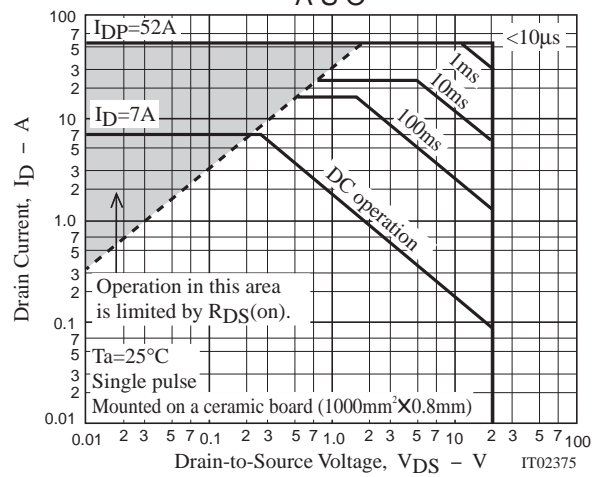
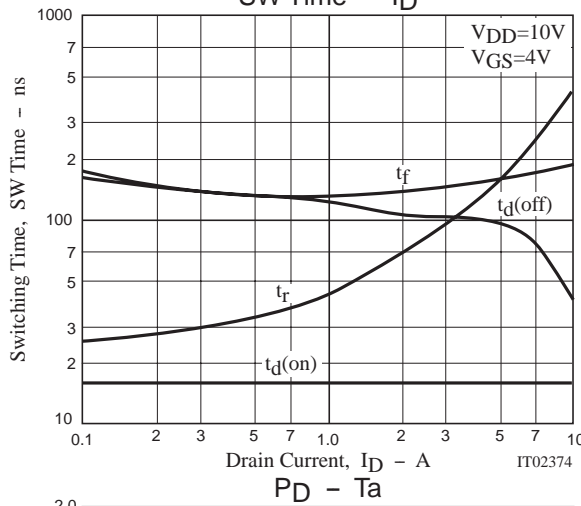
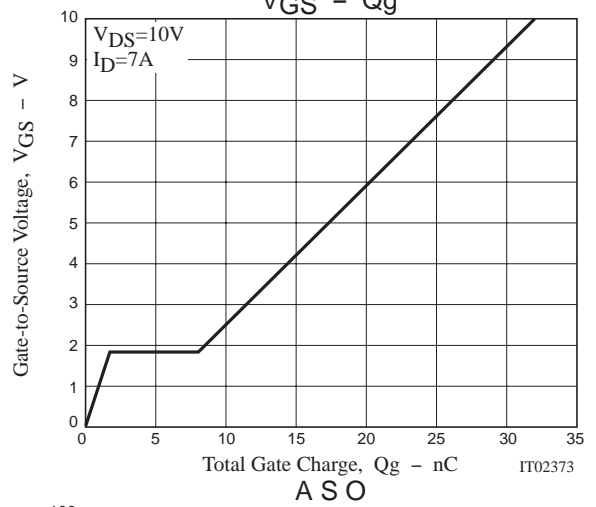
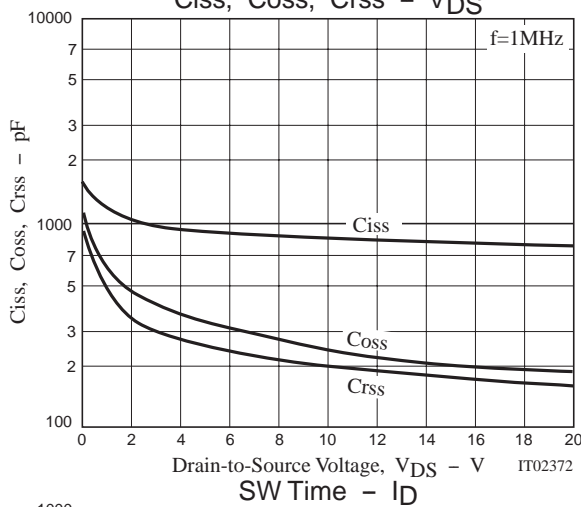
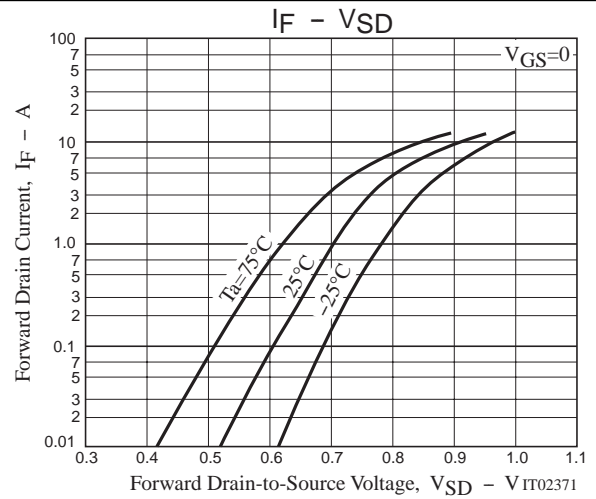
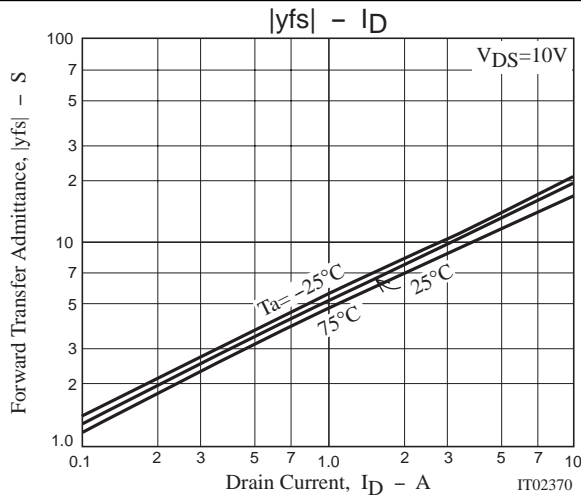
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| Parameter | Symbol | Conditions | Ratings | | | Unit |
|-------------------------------|---------------------|--|---------|------|-----|------|
| | | | min | typ | max | |
| Input Capacitance | Ciss | V _{DS} =10V, f=1MHz | | 900 | | pF |
| Output Capacitance | Coss | V _{DS} =10V, f=1MHz | | 260 | | pF |
| Reverse Transfer Capacitance | Crss | V _{DS} =10V, f=1MHz | | 200 | | pF |
| Turn-ON Delay Time | t _{d(on)} | See specified Test Circuit | | 15 | | ns |
| Rise Time | t _r | See specified Test Circuit | | 220 | | ns |
| Turn-OFF Delay Time | t _{d(off)} | See specified Test Circuit | | 75 | | ns |
| Fall Time | t _f | See specified Test Circuit | | 180 | | ns |
| Total Gate Charge | Q _g | V _{DS} =10V, V _{GS} =10V, I _D =7A | | 32 | | nC |
| Gate-to-Source Charge | Q _{gs} | V _{DS} =10V, V _{GS} =10V, I _D =7A | | 1.7 | | nC |
| Gate-to-Drain "Miller" Charge | Q _{gd} | V _{DS} =10V, V _{GS} =10V, I _D =7A | | 6.4 | | nC |
| Diode Forward Voltage | V _{SD} | I _S =7A, V _{GS} =0 | | 0.86 | 1.2 | V |

Switching Time Test Circuit





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